## NSN 5961-01-374-1230



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-374-1230 **Inclosure Material:** Metal **Overall Length:** Between 0.380 inches and 0.405 inches **Terminal Length:** Between 0.500 inches and 0.562 inches **Overall Height:** Between 0.570 inches and 0.620 inches **Overall Width:** Between 0.160 inches and 0.190 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Unthreaded hole **Features Provided:** W/heat sink **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 18.0 breakdown voltage, collector-to-emitter, base open and 36.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 amperes all primaries **Power Rating Per Characteristic:** 12.0 watts any acceptable preset **Transfer Ratio:** 5.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

No

N/a

**Unit Of Measure:** 

Demilitarization:

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